

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74VCX32FT

## Low-Voltage Quad 2-Input OR Gate with 3.6-V Tolerant Inputs and Outputs

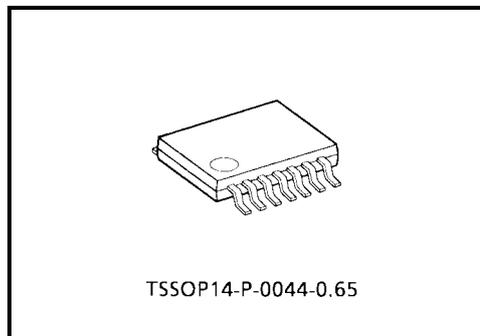
The TC74VCX32FT is a high-performance CMOS 2-input OR gate. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to 3.6 V.

All inputs are equipped with protection circuits against static discharge.

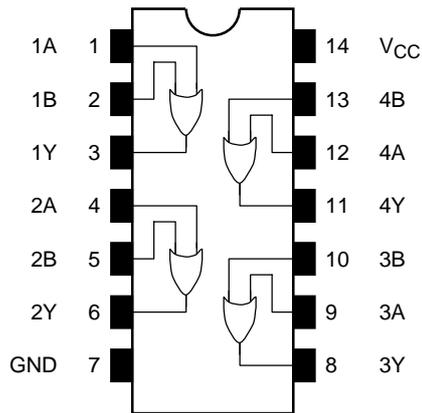
### Features

- Low-voltage operation:  $V_{CC} = 1.8$  to  $3.6$  V
- High-speed operation:  $t_{pd} = 2.8$  ns (max) ( $V_{CC} = 3.0$  to  $3.6$  V)  
:  $t_{pd} = 3.7$  ns (max) ( $V_{CC} = 2.3$  to  $2.7$  V)  
:  $t_{pd} = 7.4$  ns (max) ( $V_{CC} = 1.8$  V)
- Output current:  $I_{OH}/I_{OL} = \pm 24$  mA (min) ( $V_{CC} = 3.0$  V)  
:  $I_{OH}/I_{OL} = \pm 18$  mA (min) ( $V_{CC} = 2.3$  V)  
:  $I_{OH}/I_{OL} = \pm 6$  mA (min) ( $V_{CC} = 1.8$  V)
- Latch-up performance:  $\pm 300$  mA
- ESD performance: Machine model  $> \pm 200$  V  
: Human body model  $> \pm 2000$  V
- Package: TSSOP (thin shrink small outline package)
- 3.6-V tolerant function and power-down protection provided on all inputs and outputs

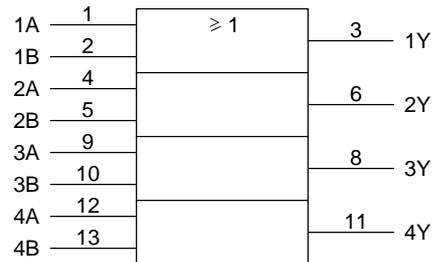


Weight: 0.06 g (typ.)

## Pin Assignment (top view)



## IEC Logic Level



## Truth Table

Inputs		Outputs
A	B	Y
L	L	L
L	H	H
H	L	H
H	H	H

## Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply voltage	$V_{CC}$	-0.5 to 4.6	V
DC input voltage	$V_{IN}$	-0.5 to 4.6	V
DC output voltage	$V_{OUT}$	-0.5 to 4.6 (Note 1)	V
		-0.5 to $V_{CC} + 0.5$ (Note 2)	
Input diode current	$I_{IK}$	-50	mA
Output diode current	$I_{OK}$	$\pm 50$ (Note 3)	mA
DC output current	$I_{OUT}$	$\pm 50$	mA
Power dissipation	$P_D$	180	mW
DC $V_{CC}$ /ground current	$I_{CC}/I_{GND}$	$\pm 100$	mA
Storage temperature	$T_{stg}$	-65 to 150	$^{\circ}C$

Note 1:  $V_{CC} = 0$  V

Note 2: High or low state.  $I_{OUT}$  absolute maximum rating must be observed.

Note 3:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$

## Recommended Operating Range

Characteristics	Symbol	Rating	Unit
Power supply voltage	$V_{CC}$	1.8 to 3.6	V
		1.2 to 3.6 (Note 4)	
Input voltage	$V_{IN}$	-0.3 to 3.6	V
Output voltage	$V_{OUT}$	0 to 3.6 (Note 5)	V
		0 to $V_{CC}$ (Note 6)	
Output current	$I_{OH}/I_{OL}$	$\pm 24$ (Note 7)	mA
		$\pm 18$ (Note 8)	
		$\pm 6$ (Note 9)	
Operating temperature	$T_{opr}$	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 10 (Note 10)	ns/V

Note 4: Data retention only

Note 5:  $V_{CC} = 0$  V

Note 6: High or low state

Note 7:  $V_{CC} = 3.0$  to 3.6 V

Note 8:  $V_{CC} = 2.3$  to 2.7 V

Note 9:  $V_{CC} = 1.8$  V

Note 10:  $V_{IN} = 0.8$  to 2.0 V,  $V_{CC} = 3.0$  V

## Electrical Characteristics

### DC Characteristics ( $T_a = -40$ to $85^\circ\text{C}$ , $2.7$ V < $V_{CC} \leq 3.6$ V)

Characteristics		Symbol	Test Condition	$V_{CC}$ (V)	Min	Max	Unit	
Input voltage	H-level	$V_{IH}$	—	2.7 to 3.6	2.0	—	V	
	L-level	$V_{IL}$	—	2.7 to 3.6	—	0.8		
Output voltage	H-level	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -100 \mu\text{A}$	2.7 to 3.6	$V_{CC} - 0.2$	—	V
				$I_{OH} = -12 \text{ mA}$	2.7	2.2	—	
				$I_{OH} = -18 \text{ mA}$	3.0	2.4	—	
				$I_{OH} = -24 \text{ mA}$	3.0	2.2	—	
	L-level	$V_{OL}$	$V_{IN} = V_{IL}$	$I_{OL} = 100 \mu\text{A}$	2.7 to 3.6	—	0.2	
				$I_{OL} = 12 \text{ mA}$	2.7	—	0.4	
				$I_{OL} = 18 \text{ mA}$	3.0	—	0.4	
				$I_{OL} = 24 \text{ mA}$	3.0	—	0.55	
Input leakage current		$I_{IN}$	$V_{IN} = 0$ to 3.6 V	2.7 to 3.6	—	$\pm 5.0$	$\mu\text{A}$	
Power-off leakage current		$I_{OFF}$	$V_{IN}, V_{OUT} = 0$ to 3.6 V	0	—	10.0	$\mu\text{A}$	
Quiescent supply current		$I_{CC}$	$V_{IN} = V_{CC}$ or GND	2.7 to 3.6	—	20.0	$\mu\text{A}$	
			$V_{CC} \leq V_{IN} \leq 3.6$ V	2.7 to 3.6	—	$\pm 20.0$		
Increase in $I_{CC}$ per input		$\Delta I_{CC}$	$V_{IH} = V_{CC} - 0.6$ V	2.7 to 3.6	—	750		

## DC Characteristics (Ta = -40 to 85°C, 2.3 V ≤ VCC ≤ 2.7 V)

Characteristics		Symbol	Test Condition		VCC (V)	Min	Max	Unit
Input voltage	H-level	V <sub>IH</sub>	—		2.3 to 2.7	1.6	—	V
	L-level	V <sub>IL</sub>	—		2.3 to 2.7	—	0.7	
Output voltage	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	2.3 to 2.7	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -6 mA	2.3	2.0	—	
				I <sub>OH</sub> = -12 mA	2.3	1.8	—	
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	2.3 to 2.7	—	0.2	
				I <sub>OL</sub> = 12 mA	2.3	—	0.4	
				I <sub>OL</sub> = 18 mA	2.3	—	0.6	
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		2.3 to 2.7	—	±5.0	μA
Power-off leakage current		I <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V		0	—	10.0	μA
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.3 to 2.7	—	20.0	μA
			V <sub>CC</sub> ≤ V <sub>IN</sub> ≤ 3.6 V		2.3 to 2.7	—	±20.0	

## DC Characteristics (Ta = -40 to 85°C, 1.8 V ≤ VCC < 2.3 V)

Characteristics		Symbol	Test Condition		VCC (V)	Min	Max	Unit
Input voltage	H-level	V <sub>IH</sub>	—		1.8 to 2.3	0.7 × V <sub>CC</sub>	—	V
	L-level	V <sub>IL</sub>	—		1.8 to 2.3	—	0.2 × V <sub>CC</sub>	
Output voltage	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	1.8	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -6 mA	1.8	1.4	—	
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	1.8	—	0.2	
				I <sub>OL</sub> = 6 mA	1.8	—	0.3	
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		1.8	—	±5.0	μA
Power-off leakage current		I <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V		0	—	10.0	μA
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		1.8	—	20.0	μA
			V <sub>CC</sub> ≤ V <sub>IN</sub> ≤ 3.6 V		1.8	—	±20.0	

## AC Characteristics (Ta = -40 to 85°C, input: tr = tf = 2.0 ns, CL = 30 pF, RL = 500 Ω)

Characteristics	Symbol	Test Condition	VCC (V)	Min	Max	Unit
Propagation delay time	t <sub>pLH</sub> t <sub>pHL</sub>	Figure 1, Figure 2	1.8	1.0	7.4	ns
			2.5 ± 0.2	0.8	3.7	
			3.3 ± 0.3	0.6	2.8	
Output to output skew	t <sub>osLH</sub> t <sub>osHL</sub>	(Note 11)	1.8	—	0.5	ns
			2.5 ± 0.2	—	0.5	
			3.3 ± 0.3	—	0.5	

For C<sub>L</sub> = 50 pF, add approximately 300 ps to the AC maximum specification.

Note 11: Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

## Dynamic Switching Characteristics (Ta = 25°C, input: tr = tf = 2.0 ns, CL = 30 pF)

Characteristics	Symbol	Test Condition	VCC (V)	Typ.	Unit
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V (Note 12)	1.8	0.25	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V (Note 12)	2.5	0.6	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V (Note 12)	3.3	0.8	
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V (Note 12)	1.8	-0.25	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V (Note 12)	2.5	-0.6	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V (Note 12)	3.3	-0.8	
Quiet output minimum dynamic V <sub>OH</sub>	V <sub>OHV</sub>	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V (Note 12)	1.8	1.5	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V (Note 12)	2.5	1.9	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V (Note 12)	3.3	2.2	

Note 12: Parameter guaranteed by design.

## Capacitive Characteristics (Ta = 25°C)

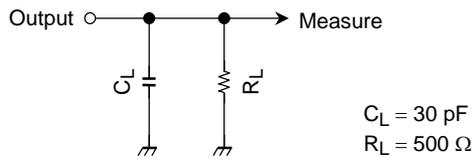
Characteristics	Symbol	Test Condition	VCC (V)	Typ.	Unit
Input capacitance	C <sub>IN</sub>	—	1.8, 2.5, 3.3	6	pF
Power dissipation capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz (Note 13)	1.8, 2.5, 3.3	20	pF

Note 13: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

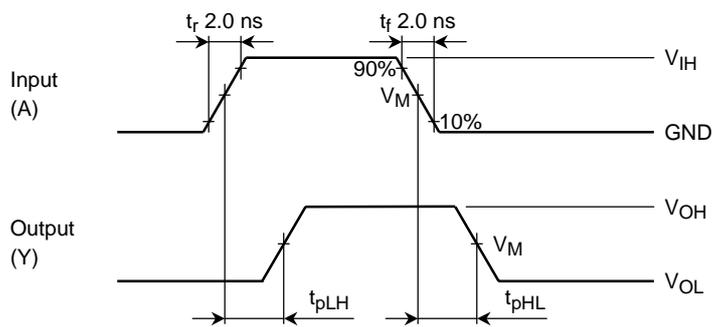
$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$$

**AC Test Circuit**



**Figure 1**

**AC Waveform**



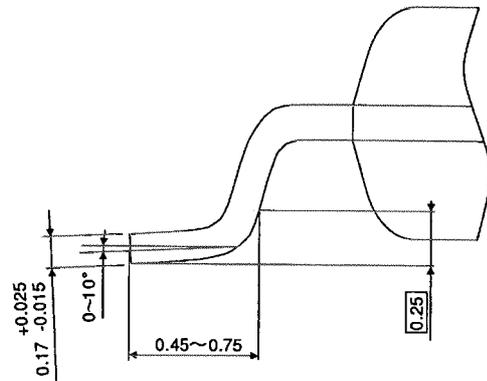
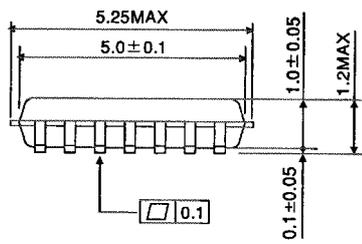
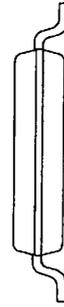
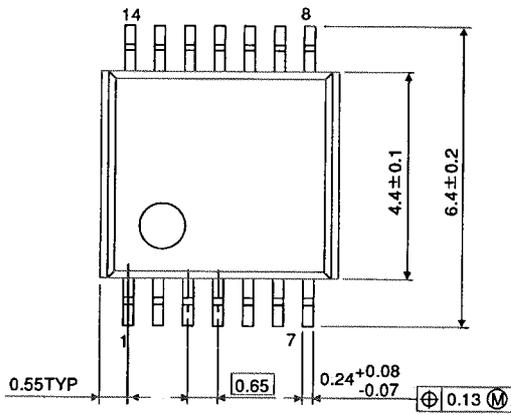
Symbol	$V_{CC}$		
	$3.3 \pm 0.3 \text{ V}$	$2.5 \pm 0.2 \text{ V}$	1.8 V
$V_{IH}$	2.7 V	$V_{CC}$	$V_{CC}$
$V_M$	1.5 V	$V_{CC}/2$	$V_{CC}/2$

**Figure 2  $t_{pLH}$ ,  $t_{pHL}$**

**Package Dimensions**

TSSOP14-P-0044-0.65

Unit : mm



Weight: 0.06 g (typ.)

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